Substitute for form 1449A/PTO				Complete if Known	
INIEO	RMATION I	MCCI	OCUDE	Application Number	New Application
		_		Filing Date	March 31, 2004
STATEMENT BY APPLICANT (suse as muany sheets as necessary)				First Named Inventor	Shunpei YAMAZAKI et al.
			(מי	Art Unit	2826
				Examiner Name	S. Wilson
Sheet	1	of	1	Attorney Docket Number	740756-2719

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Signature Considered 4/06/2005	Examiner Signature		Considered 1/06/2003
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^{*}EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

¹ Applicant's unique citation designation number (optional). ² See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. ³ Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴ For Japanese patent documents, the indication of the year of the reign of the Emperor must precede the serial number of the patent document. ⁵ Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST.16 if possible. ⁶ Applicant is to place a check mark here if English language Translation is attached